#### Features

- Single-Supply Operation from +2.5V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 13MHz (Typ@25°C)
- Low Offset Voltage: 5µV (Max@25°C)
- Quiescent Current: 1.3mA per Amplifier (Typ)
- Operating Temperature: -40°C ~ +125°C
- Zero Drift: 0.027µV/°C (Typ)

### **General Description**

- Embedded RF Anti-EMI Filter
- Small Package:

GS8557 Available in SOT23-5 and SOP-8 Packages GS8558 Available in SOP-8 and MSOP-8 Packages GS8559 Available in SOP-14 and TSSOP-14 Packages

The GS855X amplifier is single/dual/quad supply, micro-power, zero-drift CMOS operational amplifiers, the amplifiers offer bandwidth of 13MHz, rail-to-rail inputs and outputs, and single-supply operation from 2.5V to 5.5V. GS855X uses auto-zero technique to provide very low offset voltage (less than 5µV maximum) and near zero drift over temperature. Low quiescent supply current of 1.3mA per amplifier and very low input bias current make the devices an ideal choice for low offset, low power consumption and high impedance applications. The GS855X offers excellent CMRR without the crossover associated with traditional complementary input stages. This design results in superior performance for driving analog-to-digital converters (ADCs) without degradation of differential linearity.

The GS8557 Single is available in SOT23-5 and SOP-8 packages. And the GS8558 Dual is available in MSOP-8 and SOP-8 packages. The GS8559 Quad is available in Green SOP-14 and TSSOP-14 packages. The extended temperature range of -40oC to +125oC over all supply voltages offers additional design flexibility.

# Applications

- Transducer Application
- Weight Scale Sensor
- Electronics Scales
- Handheld Test Equipment

- Set-Top Boxes
- Portable/Battery-Powered Applications
- Temperature Sensors
- Laptop/Notebook Computers/TFT Panels







# **Pin Configuration**

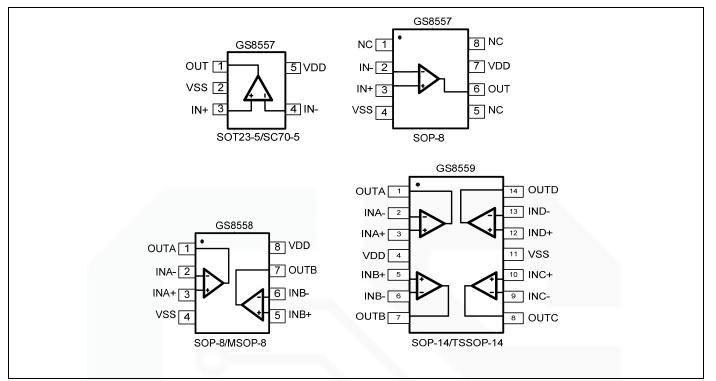


Figure 1. Pin Assignment Diagram







### **Absolute Maximum Ratings**

Condition	Min	Мах		
Power Supply Voltage (V <sub>DD</sub> to Vss)	-0.5V	+7.5V		
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V <sub>DD</sub> +0.5V		
PDB Input Voltage	Vss-0.5V	+7V		
Operating Temperature Range	-40°C	+125°C		
Junction Temperature	+160	)°C		
Storage Temperature Range	-55°C	+150°C		
Lead Temperature (soldering, 10sec)	+260	+260°C		
Package Thermal Resistance (T₄=+25℃)				
SOP-8, θ <sub>JA</sub>	125°0	125°C/W		
MSOP-8, θ <sub>JA</sub>	216°0	C/W		
SOT23-5, θ <sub>JA</sub>	190°0	C/W		
SC70-5, θ <sub>JA</sub>	333°0	333°C/W		
SOP-14, θ <sub>JA</sub>	120°(	120°C/W		
TSSOP-14, θ <sub>JA</sub>	180°0	180°C/W		
ESD Susceptibility				
НВМ	4K	V		
MM	300	V		

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **Package/Ordering Information**

MODEL	CHANNEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
000557	Cinale	GS8557-TR	SOT23-5	Tape and Reel,3000	8557
GS8557 Single	GS8557-SR	SOP-8	Tape and Reel,4000	GS8557	
000550		GS8558-SR	SOP-8	Tape and Reel,4000	GS8558
GS8558 Dual	GS8558-MR	MSOP-8	Tape and Reel,3000	GS8558	
000550	000550 0	GS8559-TR	TSSOP-14	Tape and Reel,3000	GS8559
GS8559 Quad	GS8559-SR	SOP-14	Tape and Reel,2500	GS8559	





### **Electrical Characteristics**

(At Vs = +5V, VcM = Vs/2, RL = ∞ connected to Vs/2, VouT = Vs/2 and TA =+25°C, unless otherwise noted.)

BADAMETER	0/4/201		GS8557/8558/8559				
PARAMETER	SYMBOL	CONDITIONS	ТҮР	MIN	МАХ	UNITS	
INPUT CHARACTERISTICS							
Input Offset Voltage	Vos	$V_{CM} = V_S/2$	1	-5	5	μV	
Input Bias Current	Ι <sub>Β</sub>		100			pА	
Input Offset Current	I <sub>os</sub>		10			pА	
Common-Mode Voltage Range	V <sub>см</sub>	V <sub>S</sub> = 5.5V	-0.1 to +5.6			V	
Common-Mode Rejection Ratio	CMRR	$V_{\rm S}$ = 5V, $V_{\rm CM}$ = -0.1V to 5.1V	120	100		dB	
Open-Loop Voltage Gain	A <sub>OL</sub>	Vs=5V, R <sub>L</sub> = 10k $\Omega$ , V <sub>CM</sub> = -0.1V to 5.1V	130	100		dB	
Input Offset Voltage Drift	$\Delta V_{OS} / \Delta_T$		0.027	0.13		µV/°C	
OUTPUT CHARACTERISTICS							
	V <sub>OH</sub>		4.998	4.99		V	
Output Voltage Swing from Rail	V <sub>OL</sub>	Vs=5V, RL = 100kΩ	1		10	mV	
	V <sub>OH</sub>		4.98	4.95		V	
	V <sub>OL</sub>	Vs=5V, RL = 10kΩ	10		30	mV	
	I <sub>SOURCE</sub>	N/ 5/	109				
Output Current	I <sub>SINK</sub>	Vs=5V	106			— mA	
POWER SUPPLY							
			2.5			V	
Operating Voltage Range			5.5			V	
Power Supply Rejection Ratio	PSRR	VS = +2.5V to +5.5V, VCM = +0.5V	120	100		dB	
Quiescent Current / Amplifier	Ι <sub>Q</sub>		1.3			mA	
DYNAMIC PERFORMANCE			L	1			
Gain-Bandwidth Product	GBP		13			MHz	
Slew Rate	SR	G = +1, 2V Output Step	8			V/µs	
SHUTDOWN			•	1			
Shutdown Current / Amplifier	I <sub>Q_SD</sub>		1		5	μA	

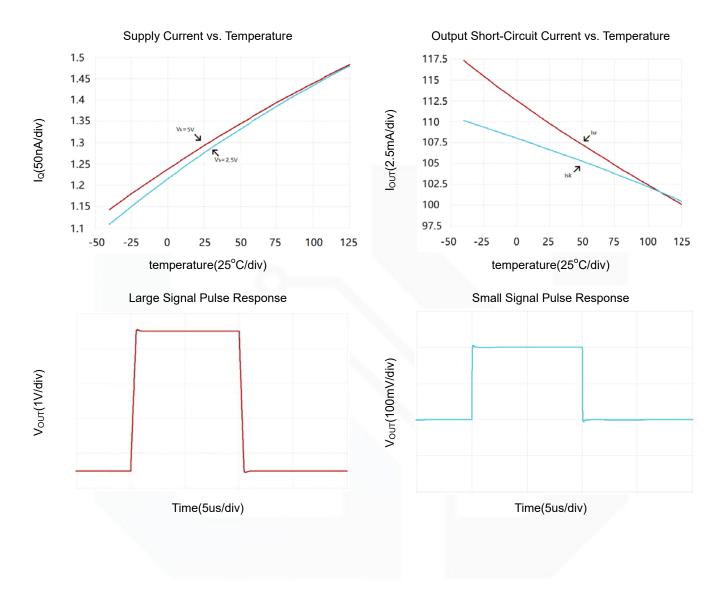






# **Typical Performance characteristics**

At T<sub>A</sub>=+25°C, V<sub>S</sub>=+5V, and R<sub>L</sub>=  $\infty$  connected to V<sub>S</sub>/2, unless otherwise noted.









### **Application Note**

#### Size

GS855X family series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the GS855X family packages save space on printed circuit boards and enable the design of smaller electronic products.

#### Power Supply Bypassing and Board Layout

GS855X family series operates from a single 2.5V to 5.5V supply or dual  $\pm 1.25V$  to  $\pm 2.75V$  supplies. For best performance, a 0.1µF ceramic capacitor should be placed close to the V<sub>DD</sub> pin in single supply operation. For dual supply operation, both V<sub>DD</sub> and V<sub>SS</sub> supplies should be bypassed to ground with separate 0.1µF ceramic capacitors.

#### Low Supply Current

The low supply current (typical 1.3mA per channel) of GS855X family will help to maximize battery life. They are ideal for battery powered systems

#### **Operating Voltage**

GS855X family operates under wide input supply voltage (2.5V to 5.5V). In addition, all temperature specifications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime

#### **Rail-to-Rail Input**

The input common-mode range of GS855X family extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### **Rail-to-Rail Output**

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of GS855X family can typically swing to less than 50mV from supply rail in light resistive loads (>10 $k\Omega$ ).

#### **Capacitive Load Tolerance**

The GS855X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

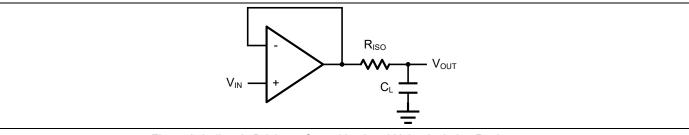


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R<sub>F</sub> provides the DC accuracy by feed-forward the V<sub>IN</sub> to R<sub>L</sub>. C<sub>F</sub>



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and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_{F}$ . This in turn will slow down the pulse response.

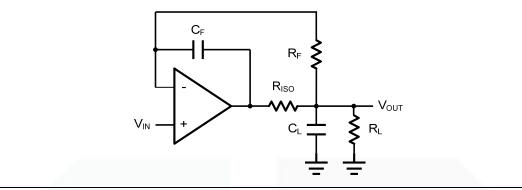


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy









# **Typical Application Circuits**

#### **Differential amplifier**

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using GS855X family.

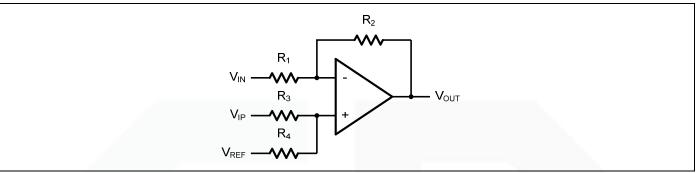


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e.  $R_1=R_3$  and  $R_2=R_4$ ), then

$$V_{\rm OUT} = \frac{R_2}{R_1} (V_{\rm IP} - V_{\rm IN}) + V_{\rm REF}$$

#### Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_c=1/(2\pi R_3C_1)$ .

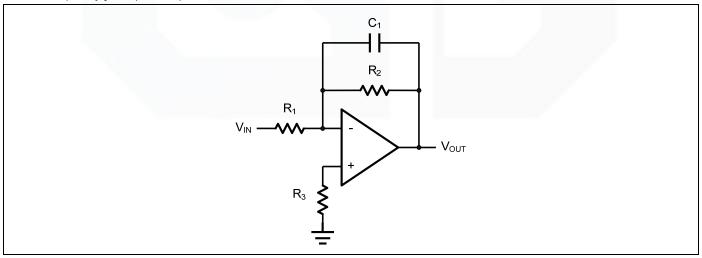


Figure 5. Low Pass Active Filter

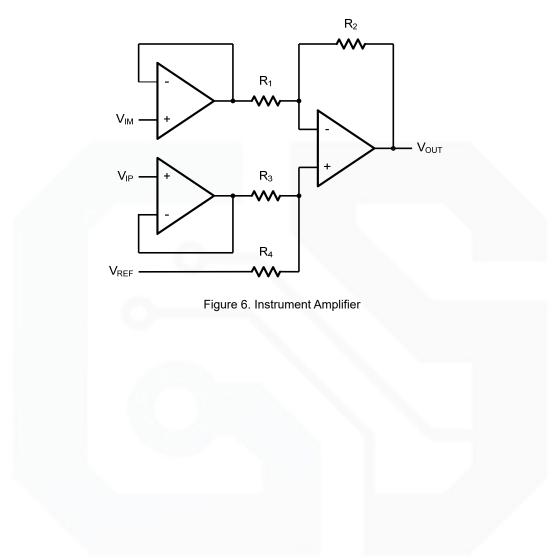






#### **Instrumentation Amplifier**

The triple GS855X family can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage followers assure the high input impedance of the amplifier.



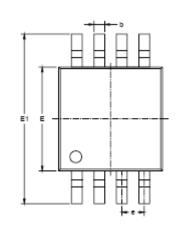




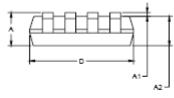


### **Package Information**

MSOP-8







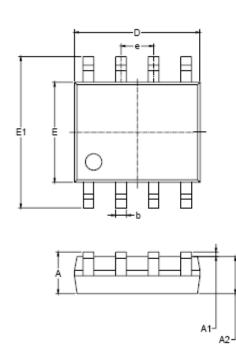
Symbol	Dimen In Milli		Dimensions In Inches		
-	MIN	MAX	MIN	MAX	
А	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
с	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
e	0.650	0.650 BSC		BSC	
L	0.400	0.800	0.016	0.031	
0	0°	6°	0°	6°	

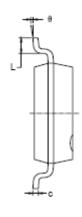






SOP-8





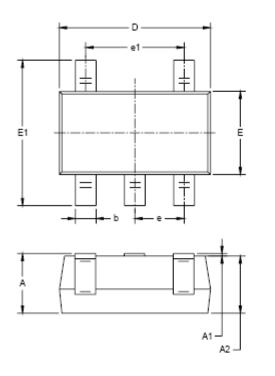
Symbol		nsions meters	Dimensions In Inches		
-,	MIN	MAX	MIN	MAX	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.27 BSC		0.050	BSC	
L	0.400	1.270	0.016	0.050	
e	0°	8°	0°	8°	

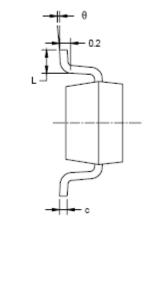






SOT23-5





Symbol		isions imeters	Dimensions In Inches		
-,	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950 BSC		0.037 BSC		
e1	1.900 BSC		0.075	BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

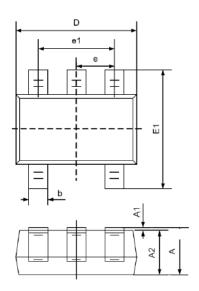


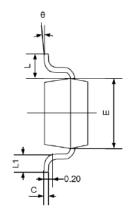






### SC70-5





# GS8557/8558/8559

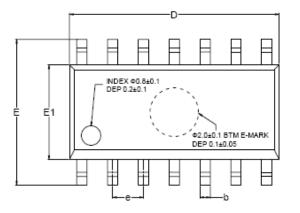
	Dimens	sions	Dimensions		
Symbol	In Millimeters		In Inches		
	Min	Min Max		Max	
А	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650T	ΥP	0.026TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525REF		0.021REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

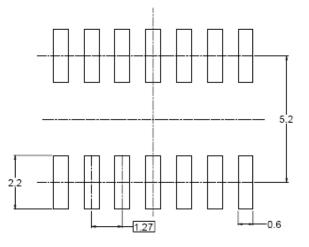




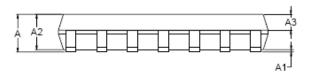


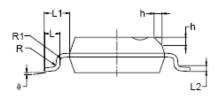






#### RECOMMENDED LAND PATTERN (Unit: mm)



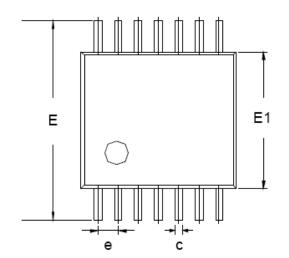


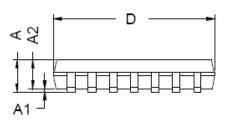
Symphol	Dimen	Dimensions In Millimeters			Dimensions In Inches		
Symbol	MIN	MOD	MAX	MIN	MOD	MAX	
А	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.25		1.65	0.049		0.065	
A3	0.55		0.75	0.022		0.030	
b	0.36		0.49	0.014		0.019	
D	8.53		8.73	0.336		0.344	
E	5.80		6.20	0.228		0.244	
E1	3.80		4.00	0.150		0.157	
е		1.27 BSC			0.050 BSC		
L	0.45		0.80	0.018		0.032	
L1		1.04 REF			0.040 REF		
L2		0.25 BSC			0.01 BSC		
R	0.07			0.003			
R1	0.07			0.003			
h	0.30		0.50	0.012		0.020	
θ	0°		8°	0°		8°	

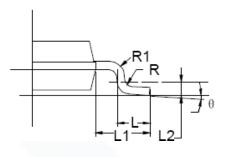












	Dimensions				
Symbol	In Millimeters				
Symbol	MIN	TYP	MAX		
A	-	-	1.20		
A1	0.05	-	0.15		
A2	0.90	1.00	1.05		
b	0.20	-	0.28		
с	0.10	-	0.19		
D	4.86	4.96	5.06		
E	6.20	6.40	6.60		
E1	4.30	4.40	4.50		
е		0.65 BSC			
L	0.45	0.60	0.75		
L1	1.00 REF				
L2	0.25 BSC				
R	0.09	-	-		
θ	0°	-	8°		



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